Form 1449\*

Atty. Docket No.: 303.676US5

Serial No. Unknown

# INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)

Applicant: Gurtej Singh Sandhu et al.

Filing Date: Herewith

Group: Unknown

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1/29/02

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Applicant: Gurtej Singh Sandhu et al.

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<sup>\*\*</sup>EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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